



Electronics Paper-I
Semiconductor Devices and Basic Electronic Systems
[CORE COURSE]

Semester: I	Credits:2	Subject Code: BS12007	Lectures: 40
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Course Outcomes:
At the end of this course, the learner will be able to:
<ul style="list-style-type: none"> • Memorize the basic knowledge of semiconductor devices and their working through characteristics and distinguish between them. • Differentiate between different types of rectifiers, Understand the concept of filter identify different voltage regulator circuits. • Describe working about BJT and its I-V Characteristics and compare and analyze different transistor configuration and amplifier • Differentiate between E-MOSFET and D-MOSFET and application as a switch

Unit 1: Semiconductor Devices	9
<ul style="list-style-type: none"> • Introduction to semiconductor: Intrinsic and extrinsic semiconductor P and N type semiconductor • Study of semiconductor devices with reference to symbol, working principle, I-V characteristics, parameters, specifications. - Rectifier diode, Zener diode, LED, Photo diode, Opto- coupler 	

Unit 2: Power Supply	12
<ul style="list-style-type: none"> • Half wave rectifier, Full wave rectifier and Bridge rectifier with RC filter and comparison of all rectifiers. • Block diagram of power supply, Voltage Regulation: Load and Line Regulation, Application of Zener as a voltage regulator, three pin regulators 	

Unit 3: Bipolar Junction Transistor and Circuits	15
<ul style="list-style-type: none"> • Bipolar Junction Transistor (BJT) symbol, types, construction, working principle, CB, CC (only concept), I-V output Characteristics of CE configuration, Definition of α, β and γ and relationship between them. • Applications of Transistor as a switch and as an amplifier. • Single stage RC coupled CE amplifier, Formula for gain, frequency response and bandwidth. 	

Unit 4: MOSFET	4
<ul style="list-style-type: none"> • Metal Oxide Semiconductor FET (MOSFET), • Enhancement and Depletion mode MOSFET, MOSFET as switch. 	

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Basic Reading:

- Working principle of Resistor, capacitor and Inductor. Knowledge of conductor, insulator and semiconductor on the basis of conduction band and valance band.

Reference Books:

- A. Motorshed , *Electronic Devices and circuits*., Prentice Hall of India.
- Albert Malvino, David J Bates, *Electronic Principles*, McGraw Hill 7th Edition. 2012
- Bernard Grob ,*Basic Electronics*., McGraw Hill Publication, 8th Revised Edition, 2010
- B.L.Theraja *Basic Electronics*, S. Chand and Co.
- Bolyestad, *Electronic Devices and Circuits*, Tata McGraw Hill.
- V.K. Mehta ,*Principals of Electronics*, S. Chand and Co.

Websites:

- <https://www.electronics-tutorials.ws/>
- <http://www.electronicsforu.com/newelectronics/default.asp>
- <https://www.instructables.com/id/Basic-Electronics/>
- <https://www.instructables.com/id/Basic-Electronics/>

E-Resources:

- <https://nptel.ac.in/courses/122/106/122106025/>
- <https://nptel.ac.in/courses/117/103/117103063/>

Contact Hours: 12 hours for Library work, practical or field work or research purposes

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Chairman (HoD)	SwateeSarwate	<i>Swatee Sarwate</i> 22/7/20	
Faculty	Anitha Menon		<i>P.A. Menon</i> 22/7/20
VC Nominee (SPPU)	Dr. Neha Deshpande	<i>Neha Deshpande</i> 22/7/20	
Subject Expert (Outside SPPU)	Dr. R.K.Kamat		<i>R.K. Kamat</i> 22/7/20
Subject Expert (Outside SPPU)	Dr. Sangeeta Kale	<i>Sangeeta Kale</i> 22/7/20	
Industry Expert	Amber Mukherjee		<i>Amber Mukherjee</i> 22/7/20
Alumni	Supriya Palande	<i>Supriya Palande</i> 22/7/20	<i>Supriya Palande</i>

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